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DDR5 SODIMM

## Product Features

- On module Power Management IC (JEDEC Standard: 1.1V)
- Operating Environment: $0^{\circ} \mathrm{C} \sim 95^{\circ} \mathrm{C}$ (Tc)
- Anti-Sulfuration Protection Against Harsh Environments
- $30 \mu$ " Gold Finger
- RoHS Compliance
- CE/FCC Certification


## Overview:

Quantum Digital Technology and the latest DDR5 SDRAM
specification has significant improvements in capacity, speed and voltage. By design the Power Management IC (PMIC) is moved onto the DIMM, reducing power management circuitry on the motherboard for unused DIMM slots in previous generations.

From JEDEC standard, the DDR5 specification is bringing the maximum potential capacity for a single DDR5 DIMM to 128 GB , a theoretical maximum transfer speed of $6400 \mathrm{MT} / \mathrm{s}$ which is doubling the rate of DDR4, along with the improved power consumption as 1.1 V . The modules are SODIMM JEDEC standards and are available in 8GB to 32GB capacities.

## Specifications:

| Interface | DDR5 |
| :--- | :--- |
| Form Factor | SODIMM |
| Data Rate | Non-ECC Unbuffered Memory |
| Capacity | 262 MT/s |
| Function | Pin Number |
| Width | 64 Bits |
| Voltage | 1.1 V |


| PCB Height | 1.18 Inches |
| :--- | :--- |
| Operating Temperature | $0^{\circ} \mathrm{C}$ to $95^{\circ} \mathrm{C}(\mathrm{Tc})$ |
| Anti-Sulfuration | Y |

## Order Information:

| Density | Component <br> Composition | Custom Part <br> Number | Rank | Voltage | Description |
| :--- | :--- | :--- | :--- | :--- | :--- |
| 8 GB | $1 \mathrm{GX16}$ | TBD | 1 Rx 8 | 1.1 V | DDR5 4800 <br> SODIMM |
| 16 GB | 2 Gx 8 | TBD | 1 Rx 8 | 1.1 V | DDR5 4800 <br> SODIMM |
| 32GB | 2 Gx 8 | TBD | 2 Rx 8 | 1.1 V | DDR5 4800 <br> SODIMM |

